TECHNOLOGY

Physical and electrical

- ▶ I-V and C-V from T=4K up to 600K.
- Transport properties (Hall, Magnetic-resistance)
- Noise (LFN/RTN) Measurements
- Nano-scale AFM measurements

Optical

- Gain / losses
- Mode profile
- M-lines
- > Spectrum analysis
- Bragg grating



Microwave

- Microwave instruments
- > RF Communication system over optical fiber
- Radiofrequency PCB prototyping
- Anechoid Chamber

ECLAT

- Lasers
- Electromagnetism
- > Cryogenic charac.
- > THz spectroscopy and Imaging



CLEAN ROOM

- Thin films deposition by PVD: RF sputtering / Joule Effect evaporation / Metallic and dielectric layers
- UV Lithography : Spin coating, photomasker / min. 0.6μm
- Wet / Dry etching (RIE, ICP), Chemistry, Nanomaterials

OTHER EQUIPMENTS

- Ion exchange technology on glass
- · Dicing, polishing, thinning, lapping



Institute of Microelectronics, Electromagnetism and Photonics

Laboratory of Hyperfrequencies and Characterization

at a glance...

- 2 Cities (Grenoble & Chambery)
- **3 Research Groups**
- 9 Research Axes
- **50 Professors, Researchers and Associates**
- 15 Technicians and engineers
- 39 PhD students
- **6 Post-Doc**

Director

A. Kaminski-Cachopo

<u>Deputy Directors</u> E. Ghibaudo (Grenoble)

F. Garet (Chambéry)









CMNE group (Micro/Nano Electronic Components)

Headed by: Q. Rafhay

- I. <u>Ultimate CMOS and alternative technologies</u> exploring device physics and applications in advanced Si and non-Si technologies
- II. <u>Integrated nanostructures and nanosystems</u> evaluating the potential of nanostructures for increased functionality of integrated circuits
- III. <u>Simulation & Modelling</u> transverse activity which works in close interaction with the two actions above
- IV. <u>Superconducting electronics</u> exploring the potential of RSFQ (Rapid Single Flux Quantum) devices and circuits

PHOTO group (PHOtonics Terahertz and Optoelectronics)

Headed by: J.-F. Roux

Headed by: P. Xavier

- I. <u>Integrated Photonic Sensors</u>
 - producing devices based on elementary building blocks: laser sources, optical detection, integrated optical functions on glass, 3D integration of semiconductors, LiNbO3 and polymers.
 - Applications to sensors, RF signal generation and telecommunications and quantum optics
- II. Characterization of THz materials and devices aiming to develop new optoelectronic components, systems and applications for the THz domain developing advanced THz characterization methods: spectroscopy, imaging etc...

2 Transverse research axis: Sensors, Optoelectronic devices and techniques

DHREAMS group

(Devices in High fRequencies for sustainable Electronics And for complex systeMS)

- I. Microwave sustainable electronics supporting the worldwide growing movement in compact and conformable connected devices
 - a. 2D/3D antennas, compact passive functions
 - b. Flexible and biosourced RF devices
 - c. RF Sensors for environment/biology
 - d. Ultra low power digital transmission systems

II. Advanced microwave characterization of complex systems

facing the problem of the complexity of RF environments and materials

- a. High frequency measurement methods
- b. Extraction of physical properties for integrated devices and very heterogeneous media